## NSN 5961-01-057-7708

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-057-7708 **Inclosure Material:** Metal **Overall Length:** 0.250 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact-darlington connected **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 350.0 collector to emitter voltage, dc **Current Rating Per Characteristic:** 20.00 amperes source cutoff current **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 21269-a700-2004 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**